IN THE CLAIMS:

1.

Please cancel claims 2-3 without prejudice, amend claims 1, 4-6, and 19-20, and add new claim 21 as follows:

(Currently Amended) A polycrystalline structure film comprising: metallic islands formed on a surface of a substrate and including atoms of at least one metallic element and molecules of a compound, the metallic islands physically spaced from each other so as to expose a metallic compound between the metallic islands, the compound of the metallic island being alternatively selected from an oxide and a nitride and consisting of elements different from the at least one metallic element; and

a seed crystal layer containing crystal grains, each of the crystal grains having grown from a corresponding one of the metallic islands so as to stand from a surface of the metallic compound; and

a magnetic crystal layer containing magnetic crystal grains, each of the magnetic crystal grains having grown from a corresponding one of the crystal grains of the seed crystal layer.

(Cancelled) 2-3.

- 4. (Currently Amended) The polycrystalline structure film according to elaim 3 claim 1, wherein said metallic compound of the metallic islands is any of Si_3N_4 , SiO_2 and Al_2O_3 .
- 5. (Currently Amended) The polycrystalline structure film according to elaim 2claim 4, wherein said metallic islands include at least one metallic element includes platinum atoms.
- 6. (Currently Amended) The polycrystalline structure film according to elaim 2claim 1, wherein said metallic islands contain said compound in a range between 5at% and 20at%.

7-18. (Cancelled)

19. (Currently Amended) The polycrystalline structure film according to claim 1, wherein each of said crystal grains eontacts withof the magnetic crystal layer is separated from another crystal grain of the magnetic crystal layer at a grain boundary, the crystal grains of the magnetic crystal layer being made of cobalt and platinum, non-magnetic materialchromium atoms diffusing along the grain boundary.

- 20. (Currently Amended) The polycrystalline structure film according to claim 19, wherein a wall of the non-magnetic material chromium atoms is formed at the grain boundary.
- 21. (New) The polycrystalline structure film according to claim 5, wherein the at least one metallic element further includes cobalt.

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